

## Innovating Energy Technology

#### **IGBT Modules**

#### **IGBT Module (V series)** 600V / 50A / IPM

#### Features

•Temperature protection provided by directly detecting

- the junction temperature of the IGBTs
- Low power loss and soft switching
- · High performance and high reliability IGBT with overheating protection
- ·Higher reliability because of a big decrease in number of
- parts in built-in control circuit

#### ■ Outline drawing (Unit : mm)



Weight:190g(typ.)

64±0.1

0

0.6 B

<del>|</del> 0.6 B

0.8±0.1

m

E



6.4±0.5



**IGBT Modules** 

#### Absolute Maximum Ratings

Tc=25°C, Vcc=15V unless otherwise specified.

Items				Min.	Max.	Units
Сс	Ilector-Emitter Voltage *1	VCES	0	600	V	
Sł	ort Circuit Voltage		Vsc	200	400	V
Ŀ,		DC	IC	-	50	Α
Inverter	Collector Current	1ms	ICP	-	100	Α
۲ ۳		Duty=100% *2	-lc	-	50	Α
-	Collector Power Dissipation	1 device *3	Pc	-	290	W
0	Collector Current	DC	IC	-	-	Α
١×		1ms	ICP	-	-	Α
Brake	Forward Current of Diode		lF	-	-	Α
	Collector Power Dissipation	1 device *3	Pc	-	-	W
	pply Voltage of Pre-Driver *4		Vcc	-0.5	20	V
In	out Signal Voltage *5		Vin	-0.5	Vcc+0.5	V
	arm Signal Voltage *6		VALM	-0.5	Vcc	V
	arm Signal Current *7		IALM	-	20	mA
	nction Temperature		Tj	-	150	°C
0	perating Case Temperature		Topr	-20	110	°C
St	prage Temperature		Tstg	-40	125	°C
Sc	Ider Temperature *8		Tsol	-	260	°C
lso	lating Voltage *9		Viso	-	AC2500	Vrms
Sc	rew Torque	Mounting (M4)	-	-	1.7	Nm

Notes

\*1: VCES shall be applied to the input voltage between terminal P-(U,V, W,B) and (U,V, W,B)-N.

\*2: Duty=125°C/Rth(j-c)D/(IF×VF Max.)×100

\*3: PC=125°C/Rth(j-c)Q (Inverter & Brake)

\*4: VCC shall be applied to the input voltage between terminal No.4 and 1, 8 and 5, 12 and 9,14 and 13.

\*5: Vin shall be applied to the input voltage between terminal No.3 and 1, 7 and 5, 11 and 9,15~18 and 13.

\*6: VALM shall be applied to the voltage between terminal No.2 and 1, 6 and 5, 10 and 9,19 and 13.

\*7: IALM shall be applied to the input current to terminal No.2,6,10 and 19.

\*8: Immersion time 10±1sec. 1time

\*9: Terminal to base, 50/60Hz sine wave 1min. All terminals should be connected together during the test.

## ■ Electrical Characteristics (Tj=25°C, VCC=15V unless otherwise specified.) ● Main circuit

	Item	Symbol		Condition	S	Min.	Тур.	Max.	Units
- La	Collector Current at off signal input	ICES	Vce	= 600V		-	-	1.0	mA
Inverter	Collector-Emitter	VCE(sat)	Ic	= 50A	Terminal	-	-	1.85	V
ž	saturation voltage	VCL(Sat)			Chip	-	1.25	-	V
<u> </u>	Forward voltage of FWD	VF	lF	= 50A	Terminal	-	-	2.1	V
		VF			Chip	-	1.6	-	V
0	Collector Current at off signal input	ICES	Vce	=		-	-	-	mA
Brake	Collector-Emitter	VCE(sat)	lc	=	Terminal	-	-	-	V
	saturation voltage	VCE(Sal)			Chip	-	-	-	V
	Forward voltage of FWD	VF	lF	=	Terminal	-	-	-	V
Forward voltage of F	Forward voltage of FVD	VF			Chip	-	-	-	V
			VDC	= 300V , Tj=12	25°C	1.1	-	-	μs
Switching time		toff	Ic	= 50A		-	-	2.1	μs
Switch		trr	Vdc If	= 300V = 50A		-	-	0.3	μs



#### **IGBT Modules**

#### • Control circuit

Item	Symbol	Conditions	6	Min.	Тур.	Max.	Units
Supply current of P-side pre-driver (per one unit)	Ісср	Switching Frequency -	= 0-15kHz	-	-	12	mA
Supply current of N-side pre-driver	Iccn	Tc=-20∼110°C		-	-	36	mA
Input signal threshold voltage	Vinth(on)	Vin-GND	ON	1.2	1.4	1.6	V
input signal threshold voltage	Vinth(off)		OFF	1.5	1.7	1.9	V

#### Protection Circuit

Item	Symbol	Co	onditions	Min.	Тур.	Max.	Units
Over Current Inverter	loc	Tj=125°C		100	-	-	Α
Protection Level Brake	100	1j=125 C	Resistance Load	-	-	-	Α
Over Current Protection Delay time	tdOC	Tj=125℃	-	-	5	-	μs
Short Circuit Protection Delay time	tsc	Tj=125°C		-	2	3	μs
IGBT Chips Over Heating	Тјон	Surface of		150	-	-	°C
Protection Temperature Level	ТJOH	IGBT Chips					
Over Heating Protection Hysteresis	ТјН			-	20	-	°C
Under Voltage Protection Level	Vuv			11.0	-	12.5	V
Under Voltage Protection Hysteresi				0.2	0.5	-	V
	talm(oc)	ALM-GND		1.0	2.0	2.4	ms
Alarm Signal Hold Time	talm(UV)	Tc=-20~110°C	、 Vcc≧10V	2.5	4.0	4.9	ms
	talm(tjoh)	1020~1100	,	5.0	8.0	11.0	ms
Resistance for current limit	Ralm			960	1265	1570	Ω

#### ■ Thermal Characteristics (Tc = 25°C)

Item			Symbol	Min.	Тур.	Max.	Units
Junction to Case	Inverter	IGBT	Rth(j-c)Q	-	-	0.43	°C/W
	IIIVEILEI	FWD	Rth(j-c)D	-	-	0.69	°C/W
	Brake	IGBT	Rth(j-c)Q	-	-	-	°C/W
	DIAKE	FWD	Rth(j-c)D	-	-	-	°C/W
Case to Fin Thermal Resistance with Compound			Rth(c-f)	-	0.05	-	°C/W

\*10: For 1device, the measurement point of the case is just under the chip.

#### ■ Noise Immunity (VDC=300V, VCC=15V)

Item	Conditions	Min.	Тур.	Max.	Units
Common mode	Pulse width 1µs,polarity ±,10min.	±2.0	-	-	kV
rectangular noise	Judge: no over-current, no miss operating				

#### Recommended Operating Conditions

Item	Symbol	Min.	Тур.	Max.	Units
DC Bus Voltage	VDC	-	-	400	V
Power Supply Voltage of Pre-Driver	Vcc	13.5	15.0	16.5	V
Switching frequency of IPM	fsw	-	-	20	kHz
Arm shoot through blocking time for IPM's input signal	tdead	1.0	-	-	μs
Screw Torque (M4)	-	1.3	-	1.7	Nm



**IGBT Modules** 



Pre-drivers include following functions

- 1. Amplifier for driver
- 2. Short circuit protection
- 3. Under voltage lockout circuit 4. Over current protection
- 5. IGBT chip over heating protection



#### **IGBT Modules**

Vinth(off)

Vinth(on)

18

150



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18

# For Fuji Electric 6MBP50VFN060-50

#### **IGBT Modules**

#### Inverter







# For Fuji Electric 6MBP50VFN060-50

**IGBT Modules** 





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#### **IGBT Modules**



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## Innovating Energy Technology

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#### **IGBT Modules**

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